# **74AUP2G240**

# Low-power dual inverting buffer/line driver; 3-state

Rev. 10 — 1 December 2020

Product data sheet

### 1. General description

The 74AUP2G240 provides the dual inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (nOE). A HIGH level at pin nOE causes the output to assume a high-impedance OFF-state.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input nOE is HIGH.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low-noise overshoot and undershoot < 10 % of  $V_{CC}$
- Input-disable feature allows floating input conditions
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



### Low-power dual inverting buffer/line driver; 3-state

# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G240DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G240GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G240GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74AUP2G240GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203

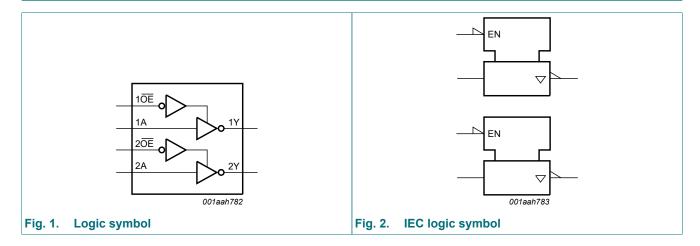
# 4. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AUP2G240DC	p40
74AUP2G240GT	p40
74AUP2G240GN	p2
74AUP2G240GS	p2

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

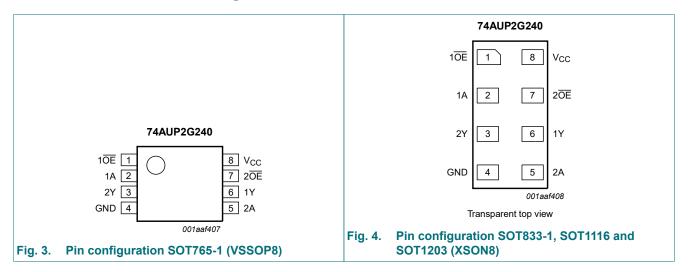
# 5. Functional diagram



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# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
10E, 20E	1, 7	output enable input (active LOW)
1A, 2A	2, 5	data input
GND	4	ground (0 V)
1Y, 2Y	6, 3	data output
V <sub>CC</sub>	8	supply voltage

# 7. Functional description

#### **Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input nOE		Output
nŌE	nA	nY
L	L	Н
L	Н	L
Н	X	Z

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# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 9. Recommended operating conditions

**Table 6. Operating conditions** 

100010 01	operating contaitions				
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
$V_{IH}$	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.30V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V

<sup>[2]</sup> For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C.

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	Vo	<sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.	75V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V		1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V		1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V		2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V		1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V		2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V		2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V		-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V		-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V		-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V		-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V		-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V		-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V		-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.1	μA
l <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$		-	-	±0.2	μA
Δl <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ to 0.2 V		-	-	±0.2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	data input; $V_1 = V_{CC} - 0.6 \text{ V}$ ; $I_0 = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	40	μA
		$\overline{\text{NOE}}$ input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	-	110	μΑ
		disabled inputs; V <sub>I</sub> = GND to 3.6 V; nOE = V <sub>CC</sub> ; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	1	μA
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$		-	0.6	-	pF
Co	output capacitance	output enabled; V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V		-	1.7	-	pF
		output disabled; $V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_O = \text{GND or } V_{CC}$		-	1.5	-	pF

Symbol	Parameter	Conditions	Min		Тур	Max	Unit
T <sub>amb</sub> = -	-40 °C to +85 °C						
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.70V	СС	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.65V	СС	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6		-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0		-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-		-	0.30V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-		-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-		-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-		-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - (	).1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7V <sub>C</sub>	С	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03		-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30		-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97		-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85		-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67		-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55		-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-		-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-		-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-		-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-		-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-		-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-		-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-		_	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-		-	0.45	V
l <sub>l</sub>	input leakage current		-		_	±0.5	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-		-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-		-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-		-	±0.6	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-		-	0.9	μA
Δl <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1] -		-	50	μA
		$\overline{\text{NOE}}$ input; $V_{I} = V_{CC} - 0.6 \text{ V}$ ; $I_{O} = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1] -		-	120	μΑ
		disabled inputs; V <sub>I</sub> = GND to 3.6 V; $\overline{\text{OE}}$ = V <sub>CC</sub> ; V <sub>CC</sub> = 0.8 V to 3.6 V	-		-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = .	-40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.75V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.70V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.25V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
lį	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
l <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.75	μΑ
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	1] -	-	75	μA
			1] -	-	180	μA
		disabled inputs; V <sub>I</sub> = GND to 3.6 V; $\overline{\text{NOE}}$ = V <sub>CC</sub> ; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	1	μA

<sup>[1]</sup> One input at  $V_{\text{CC}}$  - 0.6 V, other input at  $V_{\text{CC}}$  or GND.

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# 11. Dynamic characteristics

**Table 8. Dynamic characteristics** 

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 7.

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25	°C	T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>ar</sub> -40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	22.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.0	5.8	12.6	2.8	14.1	2.8	15.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.0	7.3	2.1	8.5	2.1	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.2	5.5	1.9	6.7	1.9	7.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.6	4.1	1.5	4.8	1.5	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.3	3.6	1.3	4.1	1.3	4.6	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6 [3]								
		V <sub>CC</sub> = 0.8 V	-	70.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	6.4	14.3	2.8	15.9	2.8	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	4.4	8.1	2.2	9.5	2.2	10.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	3.6	6.2	1.9	7.4	1.9	8.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.8	4.6	1.7	5.4	1.7	6.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.5	4.0	1.7	4.7	1.7	5.3	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 6 [4]								
		V <sub>CC</sub> = 0.8 V	-	14.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.0	4.3	7.4	2.3	8.3	2.3	9.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.6	3.2	5.2	1.7	5.9	1.7	6.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.5	3.0	4.8	1.5	5.5	1.5	6.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	2.2	3.5	1.4	4.0	1.4	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.5	3.9	1.4	4.5	1.4	5.0	ns
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	25.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.5	6.6	14.5	3.2	16.3	3.2	18.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.6	8.4	2.0	9.9	2.0	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.8	6.4	1.8	7.7	1.8	8.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.1	4.8	1.7	5.7	1.7	6.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.8	4.3	1.7	5.0	1.7	5.5	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6 [3]								
		V <sub>CC</sub> = 0.8 V	-	74.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	7.4	16.3	3.2	18.2	3.2	20.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	5.1	9.2	2.1	10.9	2.1	12.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	4.1	7.1	1.8	8.5	1.8	9.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.4	5.4	1.7	6.4	1.7	7.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	3.1	4.8	1.7	5.7	1.7	6.3	ns

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25	°C	T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>al</sub>	<sub>mb</sub> = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 6 [4]								
		V <sub>CC</sub> = 0.8 V	-	33.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.4	5.4	9.0	3.2	10.0	3.2	11.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	4.1	6.3	2.1	7.1	2.1	7.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.2	6.3	1.8	7.1	1.8	7.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	3.0	4.6	1.7	5.2	1.7	5.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.8	5.7	1.7	6.4	1.7	7.1	ns
C <sub>L</sub> = 15	pF					'	'			•
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	29.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.9	7.4	16.3	3.6	18.4	3.6	20.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.1	9.4	2.5	11.1	2.5	12.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.2	7.2	2.1	8.7	2.1	9.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.5	5.4	1.9	6.5	1.9	7.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.3	4.9	1.9	5.7	1.9	6.4	ns
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6 [3]								
		V <sub>CC</sub> = 0.8 V	-	77.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.0	8.2	18.2	3.6	20.4	3.6	22.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.6	10.3	2.5	12.2	2.5	13.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.6	7.9	2.1	9.5	2.1	10.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.9	6.0	2.0	7.2	2.0	7.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.6	5.5	1.9	6.4	1.9	7.1	ns
t <sub>dis</sub>	disable time	nOE to nY; see Fig. 6 [4]								
		V <sub>CC</sub> = 0.8 V	-	62.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	6.6	10.4	3.6	11.6	3.6	12.8	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.0	7.4	2.5	8.4	2.5	9.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.3	7.8	2.1	8.7	2.1	9.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	5.7	2.0	6.4	2.0	7.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	5.0	7.4	1.9	8.3	1.9	9.1	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	nA to nY; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	39.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	5.0	9.7	21.6	4.6	24.3	4.6	26.8	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.7	12.3	3.0	14.6	3.0	16.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.9	5.5	9.5	2.7	11.5	2.7	12.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.6	7.1	2.5	8.6	2.5	9.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.6	4.3	6.4	2.5	7.7	2.5	8.5	ns

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Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>en</sub>	enable time	nOE to nY; see Fig. 6 [3]								
		V <sub>CC</sub> = 0.8 V	-	89.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	5.2	10.6	23.8	4.6	26.7	4.6	29.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	7.3	13.2	3.0	15.7	3.0	17.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	6.0	10.2	2.7	12.3	2.7	13.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.8	5.0	7.8	2.6	9.3	2.6	10.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.8	4.8	7.1	2.6	8.4	2.6	9.3	ns
t <sub>dis</sub> disable	disable time	nOE to nY; see Fig. 6 [4]								
		V <sub>CC</sub> = 0.8 V	-	68.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	6.0	9.3	15.0	4.6	16.5	4.6	18.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.4	7.7	11.0	3.0	12.2	3.0	13.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	5.1	8.8	12.4	2.7	13.7	2.7	15.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.6	6.2	9.0	2.6	10.0	2.6	11.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.2	8.8	12.7	2.6	14.0	2.6	15.4	ns
C <sub>L</sub> = 5 pl	F, 10 pF, 15 pl	F and 30 pF				l			·	
C <sub>PD</sub>	power dissipation capacitance	$f = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}[5]$								
		V <sub>CC</sub> = 0.8 V	-	2.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

- All typical values are measured at nominal V<sub>CC</sub>.
- [2] [3]
- [4]
- All typical values are measured at nominal  $v_{CC}$ .  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PPL}$ .  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .  $t_{dis}$  is the same as  $t_{PZH}$  and  $t_{PLZ}$ .  $c_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

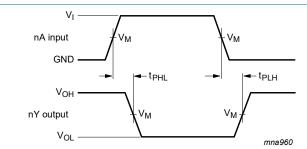
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 

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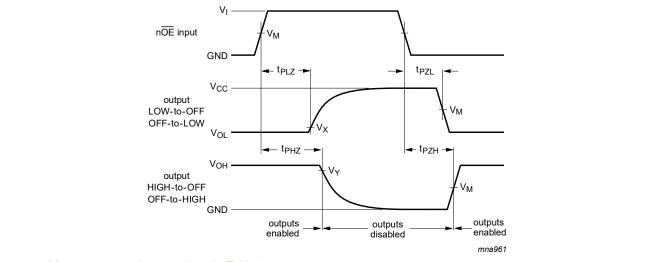
#### 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

 $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays



Measurement points are given in Table 9.

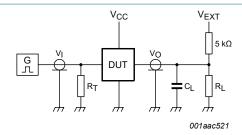
V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig. 6. 3-state enable and disable times

**Table 9. Measurement points** 

upply voltage Input			Output			
V <sub>CC</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
0.8 V to 1.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V
1.65 V to 2.7 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V
3.0 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V

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Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig. 7. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

#### Low-power dual inverting buffer/line driver; 3-state

# 12. Package outline

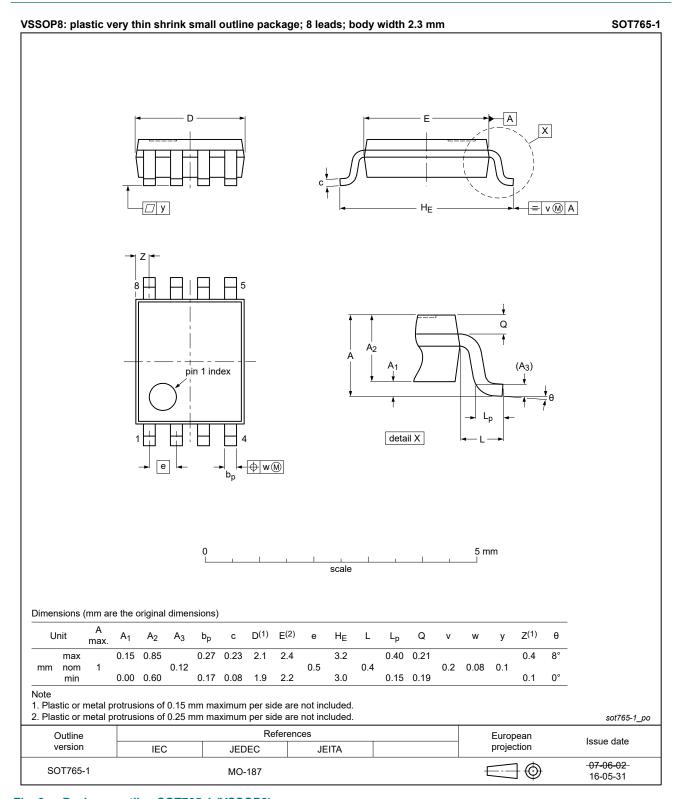


Fig. 8. Package outline SOT765-1 (VSSOP8)

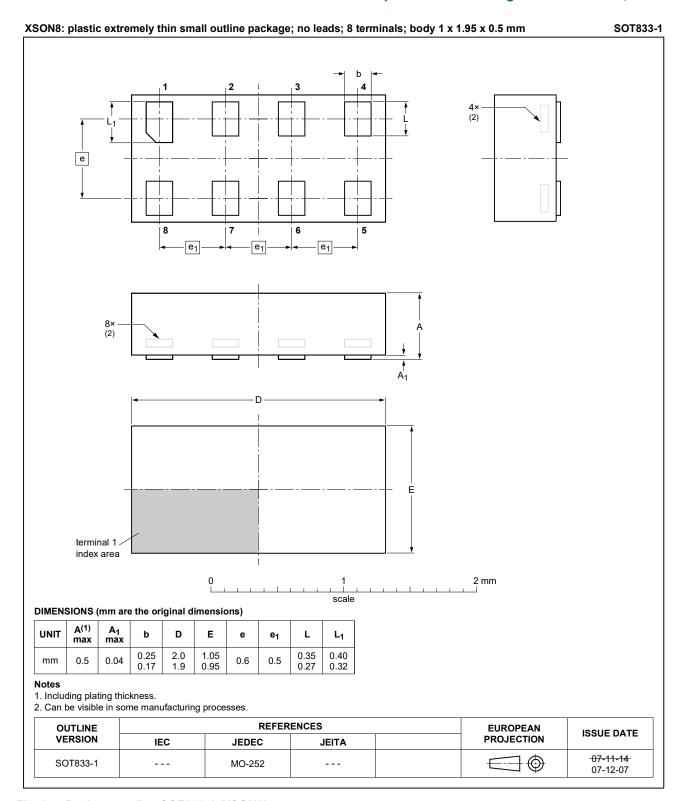


Fig. 9. Package outline SOT833-1 (XSON8)

### Low-power dual inverting buffer/line driver; 3-state

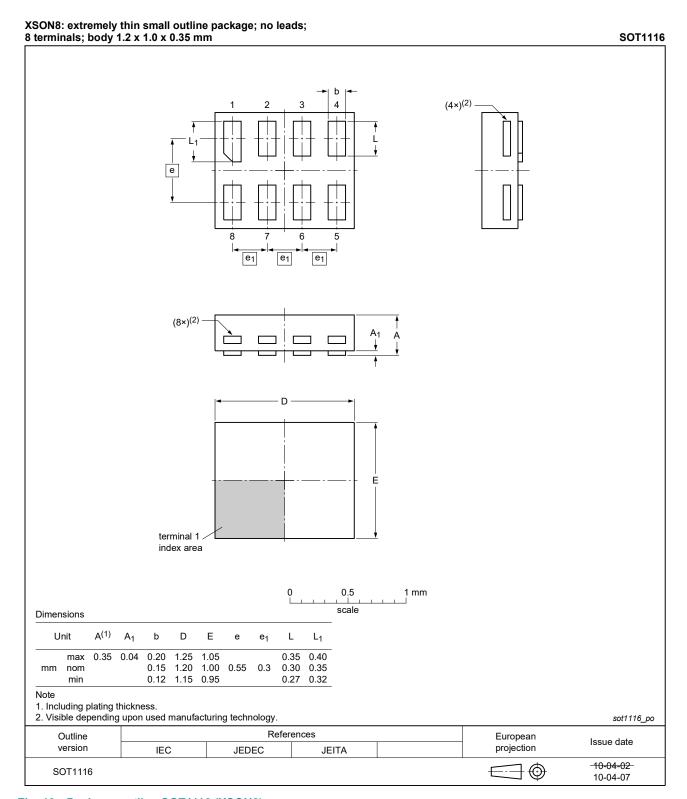


Fig. 10. Package outline SOT1116 (XSON8)

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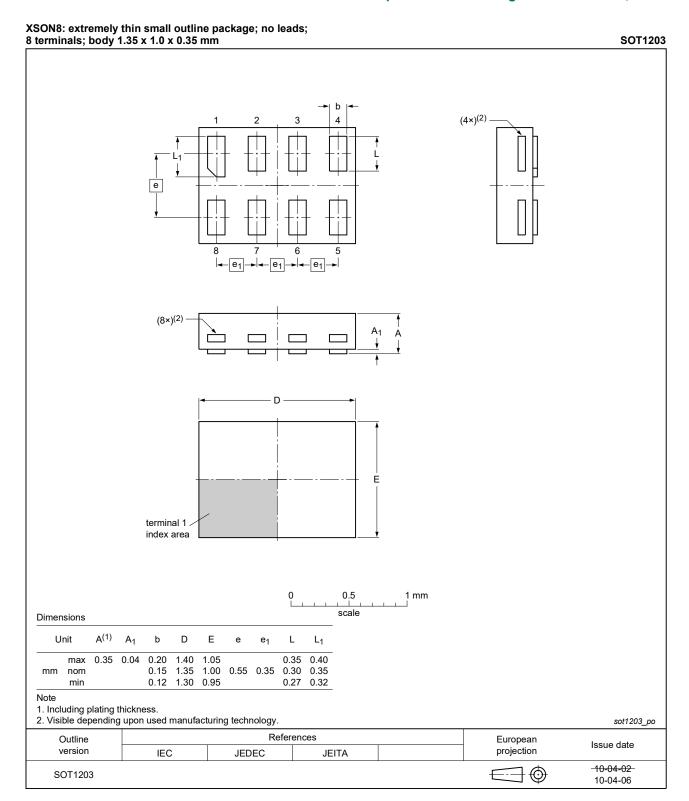


Fig. 11. Package outline SOT1203 (XSON8)

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# 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP2G240 v.10	20201201	Product data sheet	-	74AUP2G240 v.9		
Modifications:	<ul> <li><u>Section 8</u>: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> <li>Type numbers 74AUP2G240GF (SOT1089/XSON8) and 74AUP2G240GM (SOT902-2/XQFN8) removed.</li> </ul>					
74AUP2G240 v.9	20190319 Product data sheet - 74AUP2G240 v.8					
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP2G240GD (SOT996-2) removed.</li> <li>Package outline drawing SOT765-1 (VSSOP8) updated.</li> <li>Package outline drawing SOT902-2 (XQFN8) updated.</li> </ul>					
74AUP2G240 v.8	20130124 Product data sheet - 74AUP2G240 v.7					
Modifications:	For type number 74AUP2G240GD XSON8U has changed to XSON8.					
74AUP2G240 v.7	20120606	Product data sheet	-	74AUP2G240 v.6		
74AUP2G240 v.6	20111205	Product data sheet	-	74AUP2G240 v.5		
74AUP2G240 v.5	20100913	Product data sheet	-	74AUP2G240 v.4		
74AUP2G240 v.4	20090630	Product data sheet	-	74AUP2G240 v.3		
74AUP2G240 v.3	20090407	Product data sheet	-	74AUP2G240 v.2		
74AUP2G240 v.2	20080222	Product data sheet	-	74AUP2G240 v.1		
74AUP2G240 v.1	20061006	Product data sheet	-	-		

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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